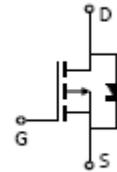


## P-Channel MOSFET



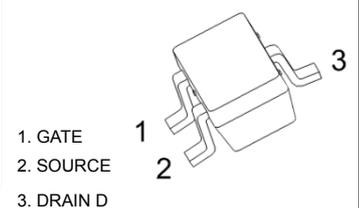
Equivalent Circuit

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
-30V	60mΩ@-10 V	-4.1A
	87mΩ@-4.5V	

### General Description

The SL2307 uses advanced trench technology to provide excellent  $R_{DS(on)}$  with low gate charge. This device is suitable for use as a load switch or in PWM applications.

### SOT-23



### Maximum ratings ( $T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Units
Drain-Source voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D$	-4.1	A
Drain Current-Pulsed	$I_{DM}$	-20	A
Power Dissipation	$P_D$	300	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	417	$^{\circ}C/W$
Junction Temperature	$T_J$	150	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55~ +150	$^{\circ}C$

**MOSFET ELECTRICAL CHARACTERISTICS**
 **$T_a=25^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Static characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = -24V, V_{GS} = 0V$			-1	$\mu A$
Gate -source leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -4.1A$			60	m $\Omega$
		$V_{GS} = -4.5V, I_D = -3A$			87	m $\Omega$
Forward tranconductance (note 1)	$g_{FS}$	$V_{DS} = -5V, I_D = -4A$	5.5			S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1		-3	V
Diode forward voltage (note 1)	$V_{SD}$	$I_S = -1A, V_{GS} = 0V$			-1	V
<b>Dynamic characteristics (note 2)</b>						
Input capacitance	$C_{iss}$	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		700		pF
Output capacitance	$C_{oss}$			120		pF
Reverse transfer capacitance	$C_{rss}$			75		pF
<b>Switching characteristics (note 2)</b>						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = -10V, V_{DS} = -15V,$ $R_L = 3.6\Omega, R_{GEN} = 3\Omega$		8.6		ns
Turn-on rise time	$t_r$			5.0		ns
Turn-off delay time	$t_{d(off)}$			28.2		ns
Turn-off fall time	$t_f$			13.5		ns

**Notes:**

1. Pulse test: Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. These parameter have no way to verify.